



#### **60V N-Channel Enhancement Mode MOSFET**

Voltage

60 V

Current

11 A

#### **Features**

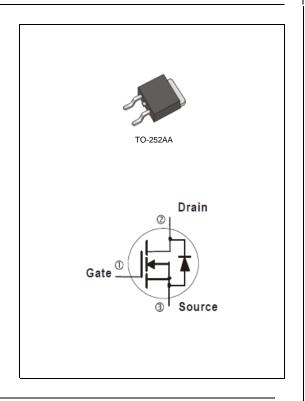
- $R_{DS(ON)}$ ,  $V_{GS}@10V$ ,  $I_D@6A<75m\Omega$
- $R_{DS(ON)}$ ,  $V_{GS}@4.5V$ ,  $I_{D}@3A<90m\Omega$
- High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

#### **Mechanical Data**

• Case: TO-252AA Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.0104 ounces, 0.297grams



# **Maximum Ratings and Thermal Characteristics** (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		$V_{DS}$	60		
Gate-Source Voltage		$V_{GS}$	<u>+</u> 20	V	
Continuous Drain Current (Note 4)	T <sub>C</sub> =25°C	l <sub>D</sub>	11		
Continuous Drain Current	T <sub>C</sub> =100°C		7	Α	
Pulsed Drain Current (Note 1)	T <sub>C</sub> =25°C	I <sub>DM</sub>	44		
Power Dissipation	T <sub>C</sub> =25°C	Po	25	14/	
	T <sub>C</sub> =100°C		10	W	
Continuous Drain Current (Note 4)	T <sub>A</sub> =25°C	I <sub>D</sub>	3.7	^	
	T <sub>A</sub> =70°C		2.9	Α	
Power Dissipation	T <sub>A</sub> =25°C	PD	2	W	
	T <sub>A</sub> =70°C		1.3		
Single Pulse Avalanche Energy (Note 6)		E <sub>AS</sub>	25	mJ	
Operating Junction and Storage Temperature Range		$T_{J}$ , $T_{STG}$	-55~150	°C	
Typical Thermal Resistance (Note 4,5)	Junction to Case	$R_{ heta JC}$	5	°C/W	
	Junction to Ambient	$R_{\theta JA}$	62.5		

• Limited only By Maximum Junction Temperature





### **Electrical Characteristics** (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =250uA	60	-	-	V	
Gate Threshold Voltage	$V_{GS(th)}$	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250uA	1	1.8	2.5		
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	$V_{GS}$ =10V, $I_D$ =6A	-	53	75	mΩ	
		$V_{GS}$ =4.5V, $I_{D}$ =3A	-	61	90		
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =60V, V <sub>GS</sub> =0V	-	-	1	uA	
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = <u>+</u> 20V, V <sub>DS</sub> =0V	-	-	<u>+</u> 100	nA	
Dynamic (Note 6)							
Total Gate Charge	Qg	V <sub>DS</sub> =48V, I <sub>D</sub> =6A, V <sub>GS</sub> =10V <sup>(Note 1,2)</sup>	-	9.3	-	nC	
Gate-Source Charge	Q <sub>gs</sub>		-	2.2	-		
Gate-Drain Charge	$Q_{gd}$		-	1.9	-		
Input Capacitance	Ciss	V <sub>DS</sub> =15V, V <sub>GS</sub> =0V, f=1MHZ	-	509	-	pF	
Output Capacitance	Coss		-	47	-		
Reverse Transfer Capacitance	Crss	I=IIVITZ	-	23	-		
Turn-On Delay Time	td <sub>(on)</sub>	.,	-	3.2	-		
Turn-On Rise Time	t <sub>r</sub>	$V_{DD}$ =30V, $I_{D}$ =1A, $V_{GS}$ =10V, $R_{G}$ =3.3 $\Omega$ (Note 1,2)	-	9.7	-		
Turn-Off Delay Time	td <sub>(off)</sub>		-	18.5	-	ns	
Turn-Off Fall Time	t <sub>f</sub>	K <sub>G</sub> =3.312	-	6.4	-		
Drain-Source Diode							
Maximum Continuous Drain-Source	,		-	-	11	А	
Diode Forward Current	I <sub>S</sub>						
Diode Forward Voltage	$V_{SD}$	I <sub>S</sub> =1A, V <sub>GS</sub> =0V	-	0.75	1	V	

#### NOTES:

- 1. Pulse width<a>300us</a>, Duty cycle<a>2%</a>.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Repetitive rating, pulse width limited by junction temperature T<sub>J(MAX)</sub>=150°C. Ratings are based on low frequency and duty cycles to keep initial T<sub>J</sub> =25°C.
- 4. The maximum current rating is package limited.
- 5. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. Guaranteed by design, not subject to production testing.





#### **TYPICAL CHARACTERISTIC CURVES**

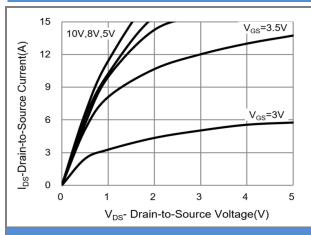
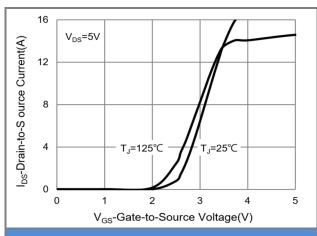


Fig.1 Output Characteristics



**Fig.2 Transfer Characteristics** 

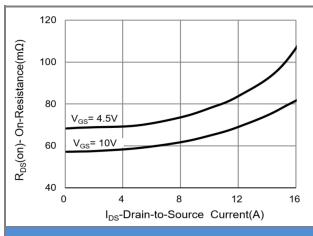


Fig.3 On-Resistance vs. Drain Current

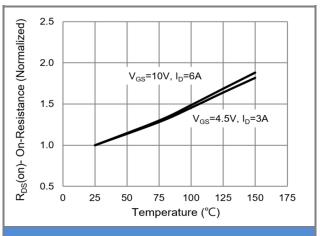


Fig.4 On-Resistance vs. Junction temperature

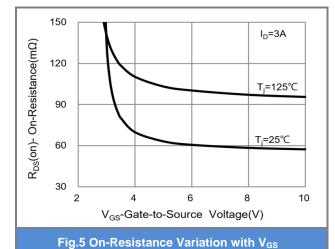
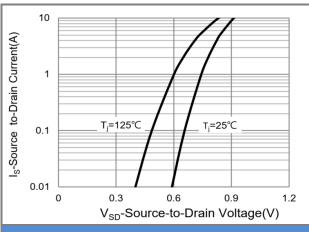


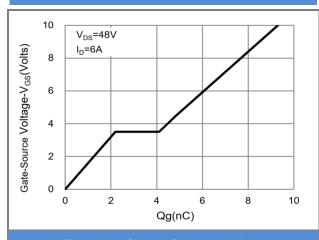
Fig.6 Source-Drain Diode Forward Voltage







#### **TYPICAL CHARACTERISTIC CURVES**



**Fig.7 Gate-Charge Characteristics** 

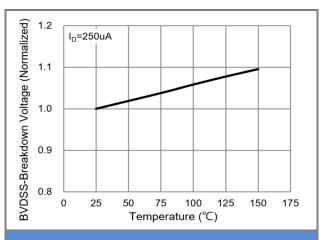


Fig.8 Breakdown Voltage Variation vs. Temperature

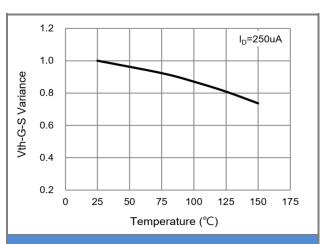


Fig.9 Threshold Voltage Variation with Temperature

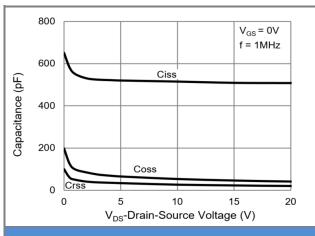


Fig.10 Capacitance vs. Drain-Source Voltage

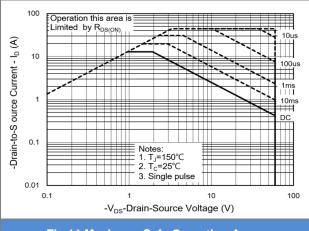


Fig.11 Maximum Safe Operating Area

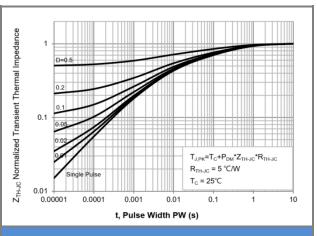


Fig.12 Normalized Transient Thermal Impedance

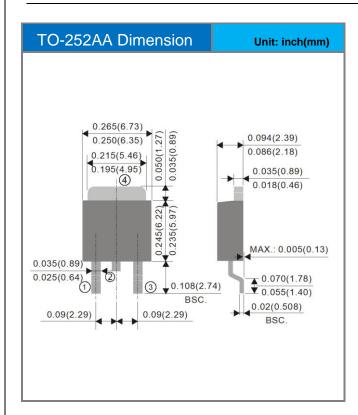


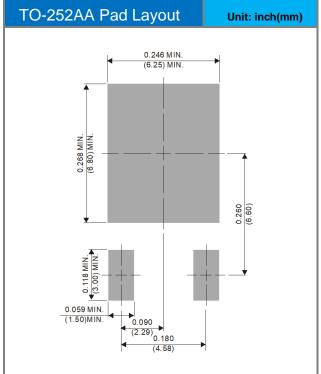


### **Part No Packing Code Version**

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJD11N06A_L2_00001	TO-252AA	3,000pcs / 13" reel	D11N06A	Halogen free

### **Packaging Information & Mounting Pad Layout**









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